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SILVACO'S ORGANIC SOLAR CELLS SIMULATION PACKAGE

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OUTLINE

1. Description of the simulation
2. Experimental vs. simulated comparison of current-voltage characteristics
 - 2.1. P3HT:PCBM solar cells
 - 2.2. Definition of E_g
 - 2.2. Light-intensity dependence
 - 2.4. Germinate pair bounding energy
 - 2.5. Case study: reduced hole mobility
 - 2.6. MDMO-PPV:PCBM solar cells : introduction of adapted Langevin recombination model
3. Novel models and tools for further optimization

Results in this presentation were simulated with the Silvaco's atlas 5.17.5.C version.

I. SIMULATED STRUCTURE

ANODE

WF=4.8 → ohmic contact and no exciton quenching at the interfaces



CATHODE

WF=3.8 → ohmic contact and no exciton quenching at the interfaces

Effective organic medium

(P3HT:PCBM or MDMO-PPV:PCBM)

$E_g=1\text{eV}^*$

$E_A=3.8\text{eV}$

$\epsilon_r=3.4^*$

$\mu_p=3 \cdot 10^{-3} \text{ cm}^2/\text{Vs}$ $\mu_n=0.9 \cdot 10^{-3} \text{ cm}^2/\text{Vs}$

Exciton diffusion length: $l=0\text{nm}$

h^+e^- distance in geminate pair:

$a=1.8\text{nm}^*$

Exciton binding energy:

$b=0.28\text{eV}$

Maximum photogeneration rate:

$G_{\text{max}}=2.2 \cdot 10^{21} \text{ cm}^{-3}\text{s}^{-1}$

Geminate decay rate:

$k_f^{-1}=100\mu\text{s}$

Exciton radiative recombination:

$k_{\text{rad}}=1\text{s}$

*Source: V. Mihailetschi and L.J.A. Koster thesis

I. PHOTON/EXCITON GENERATION RATE CALCULATION

constant photon generation profile (steady-state)

from experimental results:

$$J_{ph}@2V = J_{sat} = q \cdot G_{max} \cdot L = 105 \text{ A/m}^2$$

$$G_{max} = 2.2 \cdot 10^{21} \text{ cm}^{-3}\text{s}^{-1}$$

all photons create an exciton

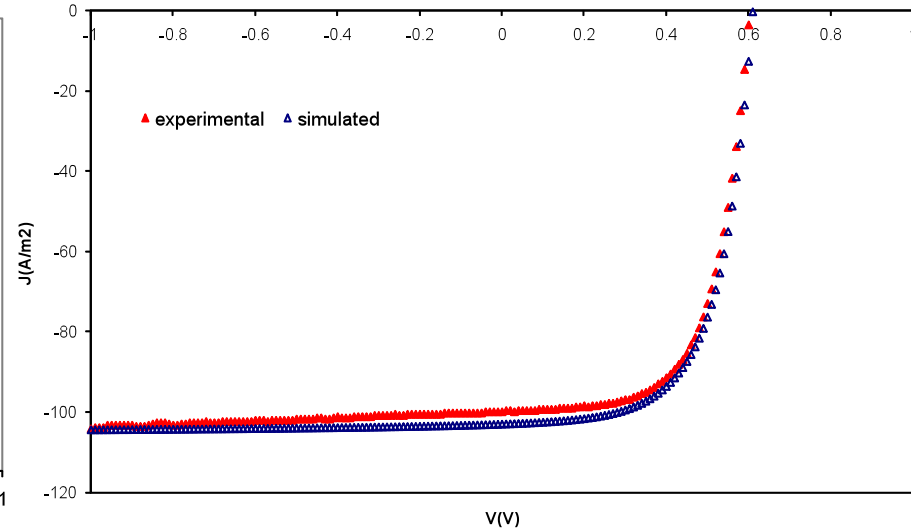
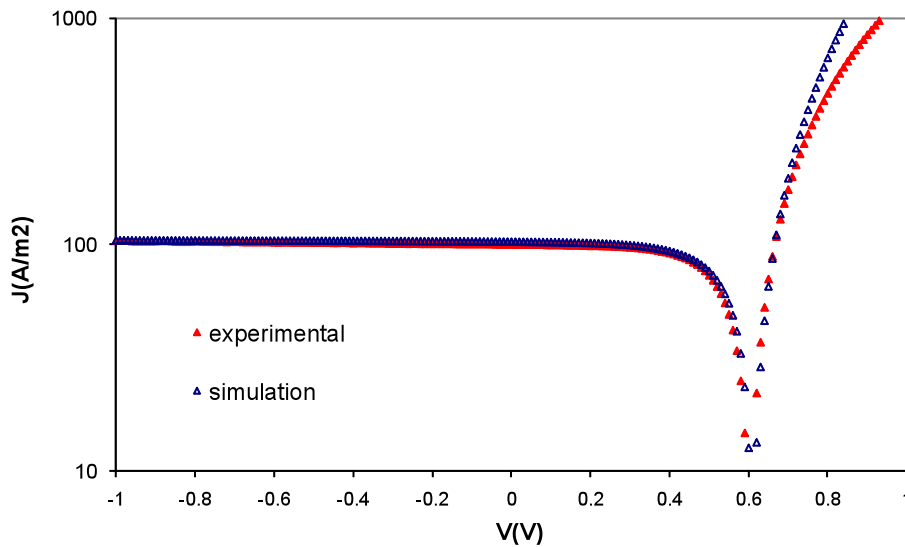
every exciton creates a geminate pair (GP)

solve the geminate pair continuity equation:

$$\frac{dS(x, y, t)}{dt} = \underbrace{R_{ST, EXCITON}}_{\text{Langevin recombination}} \underbrace{R_{L_n, p}}_{\text{Non-radiative GP decay}} - \underbrace{K_{NR, EXCITON}}_{\text{GP dissociation}} S(x, y, t) + \underbrace{G_{ph} \cdot QE \cdot EXCITON}_{\text{Photogeneration and efficiency of photon to GP transitions}} - \underbrace{\frac{PHEFF \cdot EXCITON}{TAUS \cdot EXCITON}}_{\text{Radiative GP decay and GP diffusion}} S(x, y, t) + \nabla D_s \nabla S(x, y, t)$$

2. 1. EXPERIMENTAL VS. SIMULATION

ITO/PEDOT:PSS/P3HT:PCBM/Yb/Al

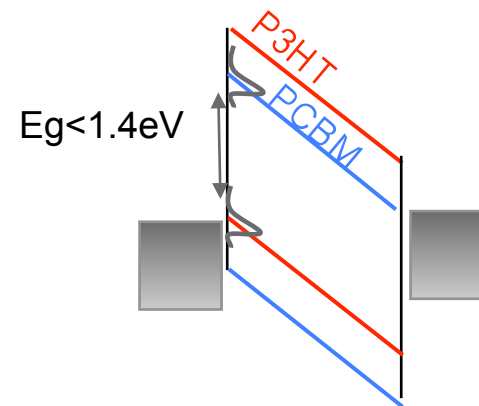
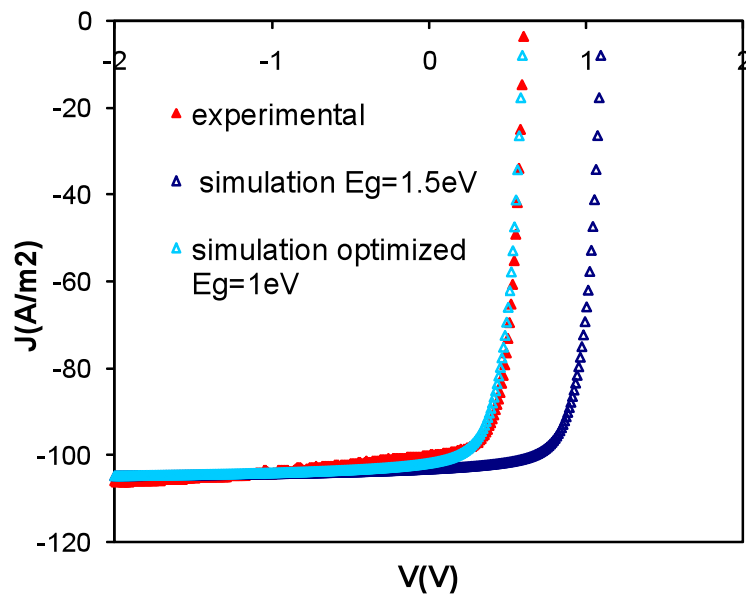


| | Voc(V) | Jsc(mA/m ²) | FF(%) | Eff(%) |
|--------------|--------|-------------------------|-------|--------|
| simulation | 0.595 | 103.0 | 64.3 | 3.94 |
| experimental | 0.603 | 100.0 | 63.7 | 3.85 |

Exact fitting parameters are available from Silvaco or from the authors.

2.2. DEFINITION OF E_g

ITO/PEDOT:PSS/P3HT:PCBM/Yb/Al

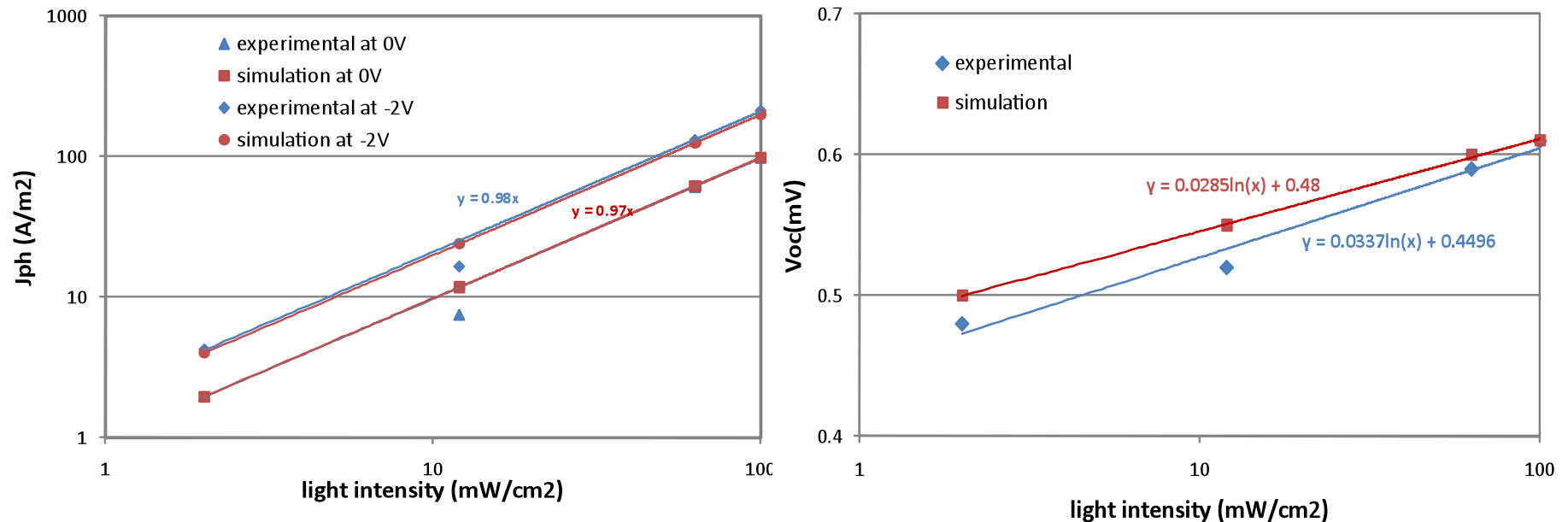


The energetic disorder characteristic of organic semiconductors (DOS), leads to at least $2 \times 0.1\text{eV}$ lowering of the effective bandgap (E_g):

$$E_g = \text{LUMO (acceptor)} - \text{HOMO (donor)} - 2 \times \text{DDOS}$$

2.3. LIGHT-INTENSITY DEPENDENCE

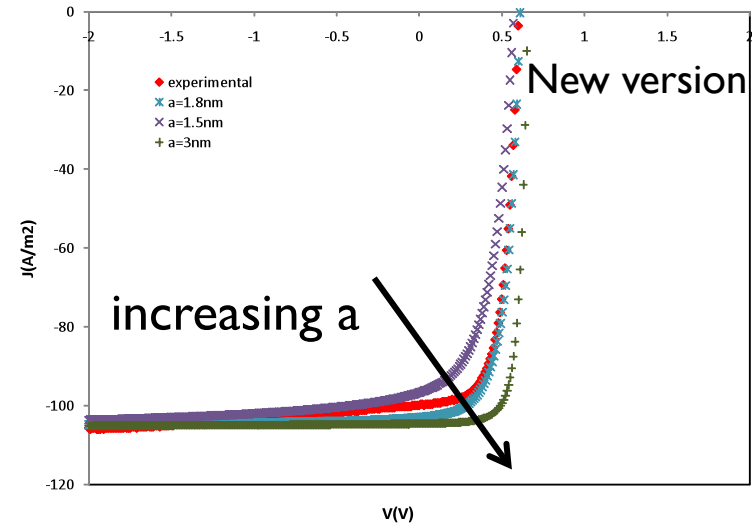
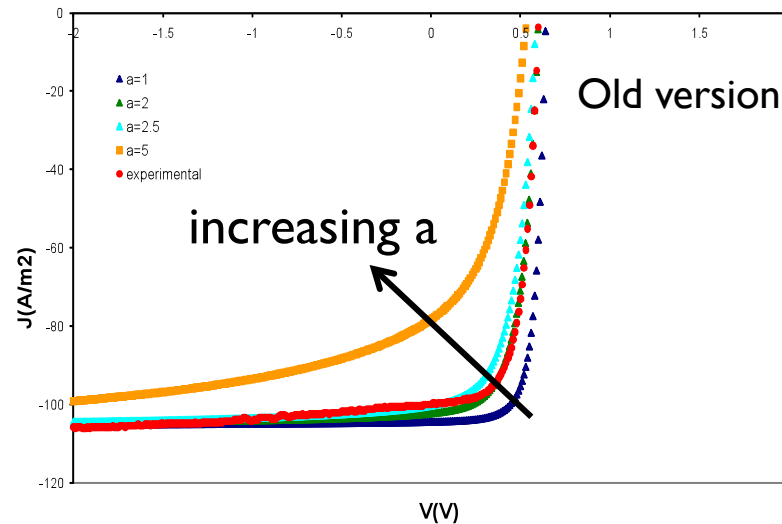
ITO/PEDOT:PSS/P3HT:PCBM/Yb/Al



Light intensity dependence of the simulated results are in good agreement with the experimental results.

2. 4. GEMINATE PAIR BOUNDING ENERGY

ITO/PEDOT:PSS/P3HT:PCBM/Yb/Al

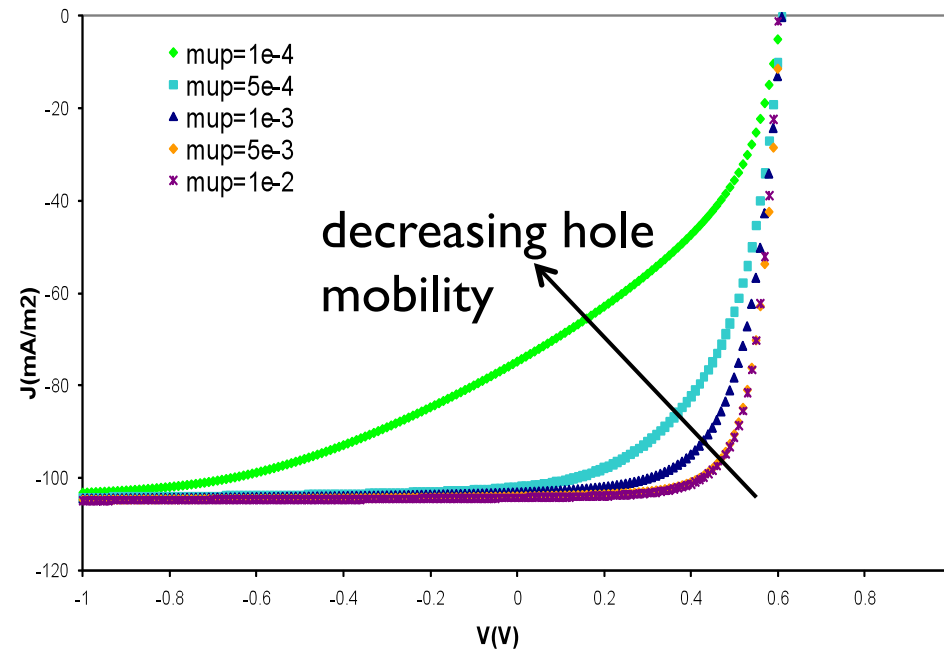


In the previous version of the simulator the geminate pair separation distance and binding energy were separate fitting parameters: producing non-physical results as this example. The new release links the two parameters with a Coulombic relation where the user can still adjust the binding energy.*

* Arkhipov et al., APL, 2003, 82, 4605

2.5. CASE STUDY: DECREASING MOBILITY

ITO/PEDOT:PSS/P3HT:PCBM/Yb/Al



Case of unbalanced charge carrier mobility leading to a space-charge limitation of the J_{ph} described by Mihailetschi et al.

The accumulation of the holes close to the anode leads to a large potential drop in this region as can be well observed with the simulation.

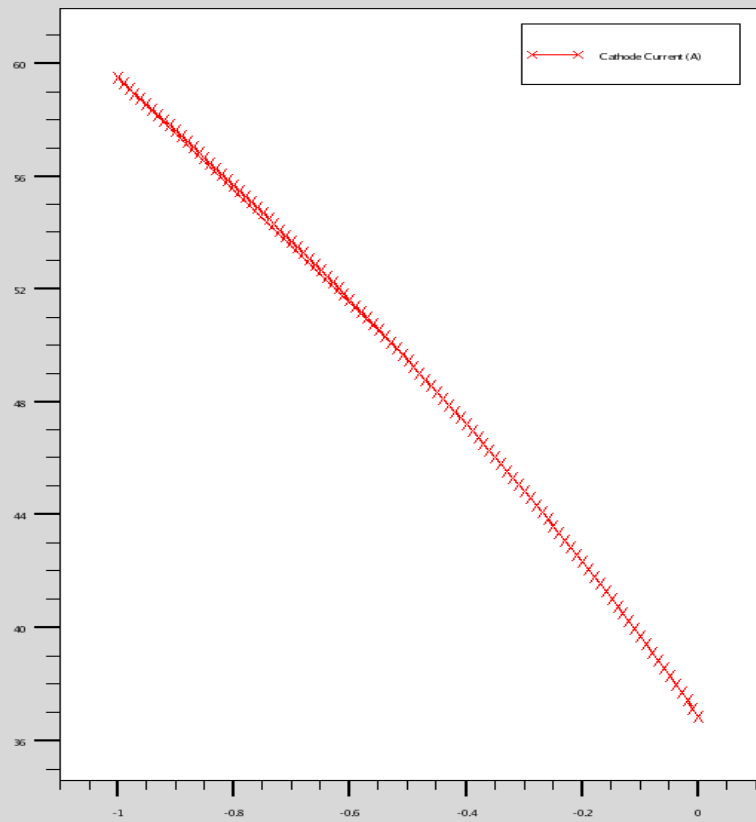
Mihailetschi et al., Phys. Rev. Lett., 2005, 94, 126602

2.5. CASE STUDY: DECREASING MOBILITY

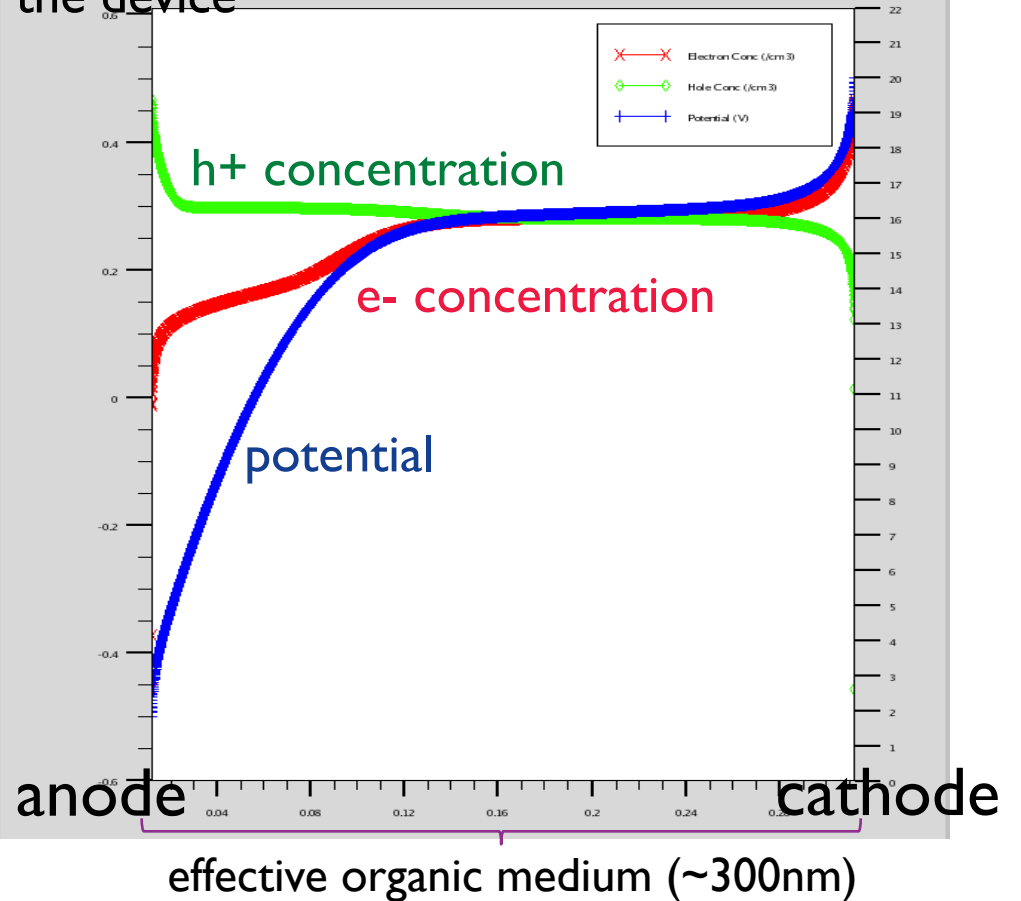
ITO/PEDOT:PSS/P3HT:PCBM/Yb/Al

$$\mu_n = 3 \cdot 10^{-3} \text{ cm}^2/\text{Vs} \quad \mu_p = 0.9 \cdot 10^{-5} \text{ cm}^2/\text{Vs}$$

JV properties of the solar cell

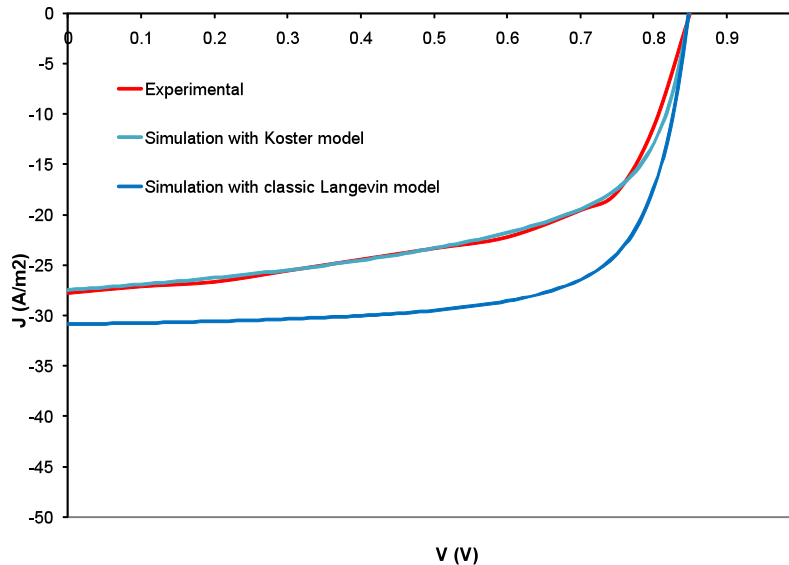


Carrier concentration and potential across the device



2.6. LANGEVIN RECOMBINATION MODEL

ITO/PEDOT:PSS/MDMO-PPV:PCBM/Yb/Al



Langevin recombination in bulk heterojunction solar cells is described by the minimum of the charge carrier mobilities. Koster et al.

The modification of the classical Langevin model is crucial in case of MDMO-PPV:PCBM cells, for example.

Koster et al., APL, 2006, 88, 052104

3. NOVEL MODELS AND TOOLS

At the donor-acceptor interface, there are permanent dipoles, and energetic disorder.

Both affect the exciton dissociation, the geminate pair dissociation (cfr. Groves) or recombination, and the charge transport of the carriers (e.g.: dipoles create an electric field which influences carrier drift).

Groves et al., Nanoletters, 2010, 10, 1063

CONCLUSIONS

- Silvaco's Organic Solar Module simulation matches experimental results in the $-IV < V < V_{oc}$ region (provided exact material parameters)
- Access to physical parameters greatly helps in-depth understanding of the device physics (for examples, distribution of carrier concentration, potential across the device or the geminate pair dissociation efficiency in function of the voltage)
- Implementation of other available models such disorder, trapping and Poole-Frenkel mobility could further bring closer experimental and simulation results.